# PI74FCT153T/253T (25 $\Omega$ Series) PI74FCT2153T/2253T

# **High-Speed CMOS Dual 4-Input Multiplexer**

### **Product Features:**

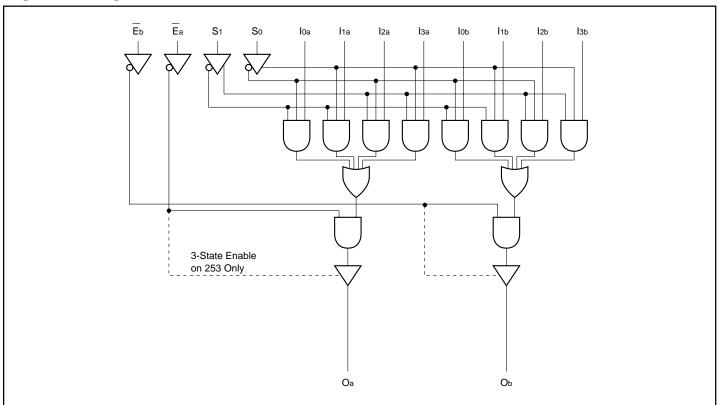
- PI74FCT153T/253T/2153T/2253T is pin compatible with bipolar FAST<sup>TM</sup> Series at a higher speed and lower power consumption
- $25\Omega$  series resistor on all outputs (FCT2XXX only)
- TTL input and output levels
- Low ground bounce outputs (25 $\Omega$  series only)
- Extremely low static power
- · Hysteresis on all inputs
- Industrial operating temperature range: -40°C to +85°C
- Packages available:
  - 16-pin 150 mil wide plastic QSOP(Q)
  - 16-pin 300 mil wide plastic SOIC (S)
  - 16-pin 150 mil wide plastic SOIC (W)

## **Product Description:**

Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.8 micron CMOS technology, achieving industry leading speed grades. All PI74FCT2XXX devices have a built-in 25-ohm series resistor on all outputs to reduce noise resulting from reflections, thus eliminating the need for an external terminating resistor.

The PI74FCT153T/253T and PI74FCT2153T/2253T are high-speed dual 4-input multiplexers. The PI74FCT153T/2153T has TTL outputs, while the PI74FCT253T/2253T has 3-state outputs. The output buffers are designed with a power-off disable allowing "live insertion" of boards when used as backplane drivers.

## **Logic Block Diagram**



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# **Product Pin Description**

Pin Name	Description
I0a-I3a, I0b-I3b	Data Inputs
S0, S1	Select Inputs
$\overline{\overline{E}}$ a, $\overline{\overline{E}}$ b	Enable Input
Oa, Ob	Data Outputs
GND	Ground
Vcc	Power

## Truth Table(1)

Inputs				Outputs					
			'153/2153			'253/	2253		
Ea	Eb	S1	S0	Oa	Ob	Oa	Ob		
Н	X	X	X	L	X	Z	X		
X	Н	X	X	X	L	X	Z		
L	L	L	L	I0a	Іоь	I0a	Іоь		
L	L	L	Н	I1a	I1b	I1a	I1b		
L	L	Н	L	I2a	I2b	I2a	I2b		
L	L	Н	Н	I3a	I3b	I3a	I3b		

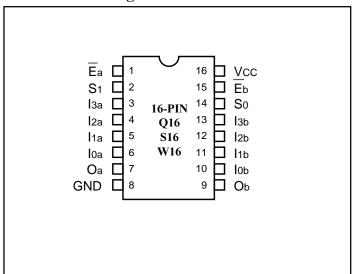
#### NOTE:

- 1. H = High Voltage Level
  - L = Low Voltage Level
  - X = Don't Care

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Z = High Impedance

# **Product Pin Configuration**





## **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature—65°C to +150°C
Ambient Temperature with Power Applied40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only)0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)0.5V to +7.0V
DC Input Voltage0.5V to +7.0V
DC Output Current
Power Dissipation

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **DC Electrical Characteristics** (Over the Operating Range, $TA = -40^{\circ}C$ to $+85^{\circ}C$ , $VCC = 5.0V \pm 5\%$ )

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
Voh	Output HIGH Voltage	$V_{CC} = Min., V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -15.0 \mathrm{mA}$	2.4	3.0		V
Vol	Output LOW Current	$V_{CC} = Min., V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 48 \text{ mA}$		0.3	0.50	V
Vol	Output LOW Current	$V_{CC} = Min., V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 12 \text{ mA} (25\Omega \text{ Series})$		0.3	0.50	V
VIH	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
VIL	Input LOW Voltage	Guaranteed Logic LOW Level			0.8	V	
IIH	Input HIGH Current	V <sub>CC</sub> = Max.	$V_{\rm IN} = V_{\rm CC}$			1	μΑ
IIL	Input LOW Current	V <sub>CC</sub> = Max.	V <sub>IN</sub> =GND			-1	μА
Іохн	High Impedance	V <sub>CC</sub> =M <sub>AX</sub> .	V <sub>OUT</sub> =2.7V			1	μА
Iozl	Output Current		V <sub>OUT</sub> =0.5V			-1	μΑ
Vik	Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18 \text{ mA}$		-0.7	-1.2	V	
Ioff	Power Down Disable	Vcc=GND, Vout=4.5V	_	_	100	μΑ	
Ios	Short Circuit Current	Vcc=Max. <sup>(3)</sup> , Vout=GND			-120		mA
VH	Input Hysteresis				200		mV

## Capacitance ( $T_A = 25^{\circ}C$ , f = 1 MHz)

Parameters <sup>(4)</sup>	Description	<b>Test Conditions</b>	Тур	Max.	Units
CIN	Input Capacitance	$V_{\rm IN} = 0V$	6	10	pF
Соит	Output Capacitance	$V_{OUT} = 0V$	8	12	pF

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#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V,  $+25^{\circ}C$  ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. This parameter is determined by device characterization but is not production tested.

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## **Power Supply Characteristics**

Parameters	Description	Test Condition	$\mathbf{s}^{(1)}$	Min.	<b>Typ</b> <sup>(2)</sup>	Max.	Units
Icc	Quiescent Power Supply Current	Vcc = Max.	$V_{IN} = GND \text{ or } V_{CC}$		0.1	500	μА
ΔΙCC	Supply Current per Input @ TTL HIGH	Vcc = Max.	$V_{IN} = 3.4V^{(3)}$		0.5	2.0	mA
Іссь	Supply Current per Input per MHz <sup>(4)</sup>	Vcc = Max., Outputs Open Other inputs at GND One Bit Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = GND$		0.15	0.25	mA/ MHz
Ic	Total Power Supply Current <sup>(6)</sup>	V <sub>CC</sub> = Max., Outputs Open fi = 10 MHz	$\begin{aligned} V_{IN} &= V_{CC} \\ V_{IN} &= GND \end{aligned}$		3.2	6.5 <sup>(5)</sup>	mA
		50% Duty Cycle Other inputs at GND One Bit Toggling	$V_{IN} = 3.4V$ $V_{IN} = GND$		3.5	7.5 <sup>(5)</sup>	

#### **Notes:**

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.

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- 2. Typical values are at Vcc = 5.0V,  $+25^{\circ}C$  ambient.
- 3. Per TTL driven input ( $V_{IN} = 3.4V$ ); all other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.
- 6. Ic =Iquiescent + Inputs + Idynamic

 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_I N_I)$ 

Icc = Quiescent Current

 $\Delta$ Icc = Power Supply Current for a TTL High Input (V<sub>IN</sub> = 3.4V)

DH = Duty Cycle for TTL Inputs High

N<sub>T</sub> = Number of TTL Inputs at D<sub>H</sub>

ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)

fi = Input Frequency

 $N_I = Number of Inputs at fi$ 

All currents are in milliamps and all frequencies are in megahertz.

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# PI74FCT153/2153T Switching Characteristics over Operating Range

			153T/2153T		153AT/	2153AT 153CT/2153CT		2153CT	
			Co	Com.		Com. Com.		m.	
Parameters	Description	Conditions <sup>(1)</sup>	Min	Max	Min	Max	Min	Max	Unit
tplh	Propagation Delay	$C_L = 50 \text{ pF}$	1.5	9.0	1.5	6.6	1.5	5.6	ns
<b>t</b> PHL	Sn to O	$R_L = 500\Omega$							
tplh	Propagation Delay		1.5	7.0	1.5	5.2	1.5	4.5	ns
<b>t</b> PHL	In to O								
tplh	Propagation Delay		1.5	7.0	1.5	5.2	1.5	4.8	ns
<b>t</b> PHL	E to O								

# PI74FCT253/2253T Switching Characteristics over Operating Range

			253T/2253T Com.		253AT/2253AT Com.		253CT/2253CT Com.		
Parameters	Description	Conditions <sup>(1)</sup>	Min	Max	Min	Max	Min	Max	Unit
<b>t</b> PLH	Propagation Delay	C <sub>L</sub> = 50 pF	1.5	9.0	1.5	6.6	1.5	5.6	ns
<b>t</b> PHL	Sn to O	$R_L = 500\Omega$							
tрlн	Propagation Delay		1.5	7.0	1.5	5.2	1.5	4.5	ns
<b>t</b> PHL	In to O								
tрzн	Output Enable Time		1.5	9.0	1.5	6.0	1.5	5.0	ns
<b>t</b> PZL	$\overline{\mathrm{E}}$ to O								
<b>t</b> PHZ	Output Disable Time(3)		1.5	7.0	1.5	6.0	1.5	5.0	ns
t <sub>PLZ</sub>	E to O								

#### Notes:

- 1. See test circuit and wave forms.
- 2. Minimum limits are guaranteed but not tested on Propagation Delays.
- 3. This parameter guaranteed but not production tested.